Effect of dopants on thermal stability and self-diffusion in iron-nitride thin films

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We studied the effect of dopants (Al, Ti, Zr) on the thermal stability of iron-nitride thin films prepared using a dc magnetron sputtering technique. Structure and magnetic characterization of deposited samples reveal that the thermal stability together with soft magnetic properties of iron-nitride thin films get significantly improved with doping. To understand the observed results, detailed Fe and N self-diffusion measurements were performed. It was observed that N self-diffusion gets suppressed with Al doping, whereas Ti or Zr doping results in somewhat faster N diffusion. On the other hand, Fe self-diffusion seems to get suppressed with any dopant of which the heat of nitride formation is significantly smaller than that of iron nitride. Importantly, it was observed that N self-diffusion plays only a trivial role, as compared to Fe self-diffusion, in affecting the thermal stability of iron-nitride thin films. Based on the obtained results, the effect of dopants on the self-diffusion process is discussed.

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I. INTRODUCTION

Nitrides of magnetic 3d transition metals are an important class of materials [1]. In particular, iron nitrides (Fe-N) have been extensively studied owing to the highest magnetic polarization of Fe as compared to other magnetic elements [2–8]. When added in a relatively small amount (<11 at. % N), N atoms get dissolved interstitially into the host metal lattice [9,10]. Due to dominant Fe-Fe interactions, N atoms are weakly bonded to Fe atoms and preserve the structure and the magnetic properties of Fe [11]. Magnetic properties of interstitial Fe-N supersedes pure Fe, giving rise to interesting effects such as giant magnetic moment [12–14], soft magnetic properties [15,16], perpendicular magnetic anisotropy [14,17,18], etc. However, interstitial Fe-N with such a large amount of N are thermodynamically unfavorable [11], and unlike iron oxides, their enthalpy of formation ($\Delta H^\gamma_f$) is at least an order of magnitude more, and even positive as in the case of $\alpha''$-Fe$_3$N$_2$ ($\Delta H^\gamma_f = 85 \pm 47$) [11]. In equilibrium, the solubility limit of interstitial N in bcc-Fe is just 0.4 at. % [1]. By using processes such as physical vapor deposition or ion implantation, bcc-Fe lattice is strained to accommodate a much higher amount of interstitial N (up to 11 at. %) [19,20]. This intrinsically makes interstitial Fe-N a weakly stable system.

In attempts to make interstitial Fe-N more stable, addition or doping of impurity element(s) was proposed in such a way that the amount of impurity must be low enough to affect the structural or the magnetic properties adversely [9,21–34]. Such impurity doped systems were termed as Fe-X-N with X = few at. % of Al, Ti, Zr, Ta, etc. Although the criteria for choosing such impurity seems to be arbitrary, variables such as affinity of X with N ($f_f$), $\Delta H^\gamma_f$ for X-N, and atomic size of dopants should have been decisive but a systematic study correlating these is still lacking. Table I compares values of $f_f$, $\Delta H^\gamma_f$, and atomic size for the most popular dopants used in the Fe-N system [11,35–37]. It was suggested in some studies that high $f_f$ and small $\Delta H^\gamma_f$ of X may result in high activation energy for diffusing N atoms, resulting in a thermally stable phase [28,35]. However, N self-diffusion measurements have not been performed.

In an extensive work by Hultman et al., N self-diffusion measurements have been carried out in transition metals such as Cr, Ti, Nb, Zr, V, etc. These transition metals generally have high $f_f$ and low $\Delta H^\gamma_f$ as compared to 3d magnetic metals [38]. In the absence of a suitable radioactive tracer for N, secondary ion mass spectroscopy (SIMS) of $^{15}$N or a nuclear reaction analysis (NRA) are the only methods to measure N self-diffusion. Since the depth resolution of these techniques is about 5 nm, N self-diffusion measurements at shorter length scales were not possible. Some attempts have been made to measure N diffusion in iron mononitride [39] using x-ray photoelectron spectroscopy (XPS) but self-diffusion cannot be measured with XPS.

Neutron reflectivity (NR) technique has emerged as an alternative to do precise diffusion measurements (depth resolution ~0.1 nm). Since scattering length density (SLD) of neutrons is...
different for isotopes, self-diffusion measurement are feasible with NR. During the last decade, NR has been used to measure self-diffusion in a variety of systems such as Fe self-diffusion in Fe-Zr, Fe-Pt, etc., Li self-diffusion in LiNbO3 single crystals [43], B self-diffusion in amorphous boron [44], and N self-diffusion in Si3N4 [45], Si-C-N [46], and iron mononitrides (Nat. % ∼ 50) [47] compounds. Here it is worth noting that even with NR, measurement of N self-diffusion in interstitial Fe-N (Nat. % ∼ 50) [48] is not as easy as in N rich compounds such as iron mononitride (Nat. % ∼ 50) or in Si3N4 due to the much smaller amount of N and a relatively poor contrast for neutrons between natN(SLD 9.36 fm) and 15N (SLD 6.3 fm). By adopting a special approach with single crystals [43], B self-diffusion in amorphous boron [44], and N self-diffusion in Si3N4 [45], Si-C-N [46], and iron mononitrides (Nat. % ∼ 50) [47] compounds. Here it is worth noting that even with NR, measurement of N self-diffusion in interstitial Fe-N (Nat. % ∼ 50) [48] is not as easy as in N rich compounds such as iron mononitride (Nat. % ∼ 50) or in Si3N4 due to the much smaller amount of N and a relatively poor contrast for neutrons between natN(SLD 9.36 fm) and 15N (SLD 6.3 fm). By adopting a special approach with single crystals 

In the present work we have addressed the above-mentioned issues in the following way: (i) We used Al and Zr dopants which have atomic sizes on extreme ends (see Table I) but similar \( \Delta H_f \), (ii) we measured N self-diffusion using NR (and SIMS) in undoped and Al, Ti, and Zr doped interstitial Fe-N, and (iii) besides, we measured self-diffusion using NR and nuclear resonance reflectivity. The doping level of \( X = \text{Al, Ti, or Zr} \) was varied according to their atomic size, affinity, and \( \Delta H_f \) of X-N. From Table I it can be seen that these parameters decrease in an order such that they are maximum for Zr followed by Ti and Al. Therefore, it is expected that small doping of Zr relative to Al would have a similar effect on thermal stability. Hence, we have chosen the atomic concentration of Al, Ti, and Zr as 5.6, 4.1, and 3.2 at. %, respectively. By doing systematic structural and magnetic characterization, we found that the thermal stability increases significantly both with Al and Zr doping. Additionally, magnetization measurements revealed formation of a stable soft-magnetic phase with dopants. To investigate the mechanism leading to enhancement in thermal stability, Fe and N self-diffusion measurements were carried out. It was found that N self-diffusion suppresses (to some extent) only with Al doping, other dopants (Ti or Zr) results in even faster diffusion. On the other hand, dopants have a much more significant effect in suppressing Fe self-diffusion. It was found that N diffusion takes place through an interstitial exchange mechanism, and during this process both structure and magnetic properties remain unaffected. This result is in contradiction with the assumption that N diffusion leads to thermal instability in the Fe-N system. We found that structural instabilities are more correlated with Fe self-diffusion rather than N self-diffusion. Based on obtained results, the effect of dopants on thermal stability and self-diffusion is discussed in this work.

### Table I. Atomic radius \( (r) \), heat of formation \( (\Delta H_f) \), and affinity \( (f) \) of X-N with respect to Fe-N.

<table>
<thead>
<tr>
<th>Element</th>
<th>( r ) (pm)</th>
<th>( \Delta H_f ) (kJ mol(^{-1}))</th>
<th>( f )</th>
</tr>
</thead>
<tbody>
<tr>
<td>Zr</td>
<td>206</td>
<td>-360</td>
<td>-0.63</td>
</tr>
<tr>
<td>Ti</td>
<td>176</td>
<td>-338</td>
<td>-0.53</td>
</tr>
<tr>
<td>Ta</td>
<td>200</td>
<td>-237</td>
<td>-0.032</td>
</tr>
<tr>
<td>Al</td>
<td>118</td>
<td>-321</td>
<td>-0.028</td>
</tr>
<tr>
<td>Fe</td>
<td>146</td>
<td>-10</td>
<td>-</td>
</tr>
</tbody>
</table>

II. EXPERIMENT

Fe-X-N thin film samples with \( X = \text{Al, Ti, or Zr} \) were deposited using a dc-magnetron sputtering technique simultaneously on Si(100) and float glass substrates at room temperature. Pure Fe, [Fe+Al], [Fe+Ti], and [Fe+Zr] composite targets were sputtered using a mixture of \( N_2 \) (1.5 sccm) and Ar (8.5 sccm) gases. To get the desired composition of Al, Ti, and Zr, relative coverage of Al, Ti, or Zr on Fe target was varied taking into account their relative sputter yields. Composition of deposited samples was measured using energy dispersive x-ray analysis and secondary neutral mass spectroscopy. It comes out to be 5.6(±1.2) at. % for Al, 4.1(±1.4) at. % for Ti, and 3.2(±1.3) at. % for Zr. The composition of nitrogen was measured with SIMS using a reference sample of known composition and comes out to be ∼11 at. % (±1) in all the samples. This was also confirmed using conversion electron Mössbauer spectroscopy in the undoped sample. A base pressure of about \( 1 \times 10^{-7} \) mbar was achieved prior to the deposition. During the deposition, partial pressure in the chamber was about \( 4 \times 10^{-3} \) mbar. More details about the deposition system are given elsewhere [10,47].

Multilayer samples with nominal structure: substrate[\([\text{Fe-X-N(6 nm)}]^{10}[\text{Fe-X-N(6 nm)}]\), substrate[\([\text{Fe-X-natN(9 nm)}]^{15}[\text{Fe-X-natN(9 nm)}]\), were prepared for Fe and N self-diffusion measurements using neutron reflectivity, with \( X = 0, \text{Al, Ti, and Zr} \). Here \( \text{“nat”} \) indicates isotopes of Fe and N obtained in natural abundance. Isotope enrichment of \(^{57}\)Fe layers exceeds to about 95%, and that of \(^{15}\)N is about 98%. For N diffusion measurements with SIMS a special trilayer structure: substrate[\([\text{Fe-X-natN(110 nm)}]^{10}[\text{Fe-X-natN(110 nm)}]\), with \( X = 0, \text{Al, and Zr} \) was deposited. Such structure is expected to give a peak when looking at \(^{15}\)N depth profile. For Fe diffusion measurements with nuclear resonance reflectivity, substrate[\([\text{Fe-N(2.2 nm)}]^{15}[\text{Fe-N(2.2 nm)}]\), and substrate[\([\text{Fe-Al-N(2 nm)}]^{15}[\text{Fe-Al-N(2 nm)}]\), samples were deposited. All samples were deposited using identical deposition conditions. Structural and magnetic characterization shown in this work was carried out on chemically homogeneous isotopic multilayer \((Fe^{\text{nat}}/Fe^{\text{nat}})\) samples with total thickness of about 120 nm. Samples with \( X = 0, \text{Al, Zr, and Ti} \) are named as Fe-N, Fe-Al-N, Fe-Zr-N, and Fe-Ti-N, respectively throughout this work.

Structural characterization was done using x-ray diffraction (XRD) on a Bruker D8 Advance x-ray diffractometer with Cu \( K\alpha \) x-ray source in \( \theta-2\theta \) geometry. For a detailed study of the microstructure of the samples transmission electron microscopy measurements were carried out using a Tecnai-G2-20 TEM operating at 200 kV. Magnetic properties were studied using a Quantum Design superconducting quantum interference device-vibrating sample magnetometer (S-VSM) and conversion electron Mössbauer spectroscopy (CEMS). Self-diffusion measurements of Fe was performed using polarized neutron reflectivity (PNR) and nuclear resonance reflectivity (NRR). For N self-diffusion measurements PNR and SIMS techniques were used. The PNR measurements were carried out on AMOR reflectometer at SINQ, PSI Switzerland. A magnetic field of about 400 kA/m was applied to saturate the samples magnetically. For diffusion
measurements only spin-up reflectivity were used. The NRR measurements were performed using 14.4 keV radiation at P01 beamline, PETRA III, DESY, Germany. SIMS measurements were performed on a Hiden Analytical SIMS Workstation. A base pressure of $8 \times 10^{-10}$ mbar was achieved in the SIMS chamber. A beam of O$_2^+$ primary ions (energy 5 keV and current 400 nA) was used to sputter samples. During measurements pressure in the chamber was about $8 \times 10^{-8}$ mbar. To investigate the thermal stability ex situ annealing of samples was performed for about 2 h in a separate vacuum furnace.

III. RESULTS

A. X-ray diffraction

Figures 1(a)–1(c) show the XRD patterns of Fe-N, Fe-Al-N, and Fe-Zr-N samples in the as-deposited state and after annealing at various temperatures. XRD patterns taken at selected temperatures are shown in the figure. From Fig. 1(a) it can be seen that in the as-deposited state distinct broad peaks corresponding to bcc $\alpha$-Fe(N) and $\alpha''$-Fe$_{16}$N$_2$ phase are appearing [14]. It is known that in these phases nitrogen atoms are occupied within the interstitial sites of Fe lattice in random and ordered fashion, respectively [49]. With annealing up to 450 K, peak intensity increases and the width reduces indicating an enhancement in nitrogen ordering. Above this temperature $\alpha''$ phase almost disappears. With further annealing, intensity of the peak corresponding to $\gamma'$-Fe$_4$N rises implying growth of the $\gamma'$ phase. Contrary to this, the behavior of Fe-Al-N and Fe-Zr-N samples are different. From Figs. 1(b) and 1(c) it can be seen that in the as-deposited state, only peaks corresponding to $\alpha$-Fe(N) phase are observed. It appears that the doping has diminished N ordering that was observed in the undoped sample. Annealing of the samples up to 500 K shows no change in the XRD pattern. Moreover, no extra peaks corresponding to any other phases can be seen even after 625 K. This indicates that the thermal stability of the films gets significantly improved with doping. From (110) reflection, average crystallite size in the samples was calculated using Scherrer formula [50] and found to be 15 and 9 nm for Fe-Al-N and Fe-Zr-N samples, respectively. Moreover, lattice constant ($a$) of doped samples in the as-deposited state is compared with undoped samples. It was observed that with Al doping the average unit cell volume of Fe gets reduced by about 0.5%, whereas, in case of Zr, it expands by about 2%. These results can be attributed to the varied atomic size of Al and Zr with respect to Fe. For doped samples it can be seen that the peak position corresponding to the (110) reflection shifts to higher 2$\theta$ above 500 K. This indicates that the thermal stability of the films gets significantly improved with doping. From (110) reflection, average crystallite size in the samples was calculated using Scherrer formula [50] and found to be 15 and 9 nm for Fe-Al-N and Fe-Zr-N samples, respectively. Moreover, lattice constant ($a$) of doped samples in the as-deposited state is compared with undoped samples. It was observed that with Al doping the average unit cell volume of Fe gets reduced by about 0.5%, whereas, in case of Zr, it expands by about 2%. These results can be attributed to the varied atomic size of Al and Zr with respect to Fe. For doped samples it can be seen that the peak position corresponding to the (110) reflection shifts to higher 2$\theta$ above 500 K. Figure 1(d) shows variation of the lattice constant with annealing temperature for Fe-Al-N and Fe-Zr-N samples. Up to 575 K $a$ remains almost constant with Al doping, while it shows a marginal increase above 400 K and a steep decrease above 575 K. Whereas with Zr doping a steep decrease in $a$ starts already at 500 K. It signifies that Al doping results in relatively superior structural stability.
FIG. 2. TEM micrographs and corresponding electron diffraction rings of as-deposited Fe-N [(a1), (a2)], Fe-Al-N [(b1), (b2)], and Fe-Zr-N [(c1), (c2)] thin films.

B. Transmission electron microscopy

To get more insight about the microstructure of the samples, TEM measurements were carried out in as-deposited samples. Figure 2 shows TEM micrographs and corresponding electron diffraction (ED) rings of Fe-N [(a1), (a2)], Fe-Al-N [(b1), (b2)], and Fe-Zr-N [(c1), (c2)] samples. It can be seen that the microstructure of the undoped sample is different from doped samples. Upon doping granular microstructure appears with an average grain size of about 15 nm in Al doped samples and about 10 nm in Zr doped samples. In an undoped sample, grain size is typically about 6 nm. These values of grain size correlate very well with those obtained from XRD measurements. The ED rings of undoped as well as doped samples were indexed corresponding to bcc $\alpha$-Fe(N). It may be noted that the (200) reflection corresponding to $\alpha$-Fe(N) phase, overlaps with the (004) reflection of $\alpha''$-Fe$_{16}$N$_2$ [13]. A closer look at the intensity distribution of diffraction rings reveals that it is slightly more inhomogeneous in an undoped sample. This could be due to texturing in the growth. Therefore, our TEM measurements show that the microstructure of undoped and doped samples is similar and the differences obtained are only of grain size and texturing. Besides, diffraction rings corresponding to any other iron nitride can neither be seen in undoped nor in Al or Zr doped samples.

C. Magnetic measurements

We performed PNR measurements on as-deposited samples. It is known that for magnetic thin films, PNR is a unique technique to measure the magnetic moment very precisely irrespective of sample dimension. The difference between the critical edges of spin-up (Fig. 3) and spin-down (not shown) reflectivities provide information about the magnetic moment, as samples were magnetically saturated [51]. Here the observed Bragg peak is due to bilayer periodicity of $^{57}$Fe/$^{nat}$Fe having different neutron scattering length contrast. To obtain information about the bilayer thickness and magnetic moment, PNR data were fitted using SimulReflc software [52]. For Fe-N, Fe-Al-N, and Fe-Zr-N samples obtained bilayer thickness are 13, 13.1, and 12.3 nm, and value of the magnetic moment is 1.8, 1.7, and 1.65 $\mu_B$, respectively. These values of magnetic moment are in agreement with those reported for the Fe-N system having a similar amount of nitrogen [10,53,54].

To investigate the implication of doping on magnetic properties, we also did M-H (magnetization-applied magnetic field) measurements. Figures 4(a)–4(c) show normalized M-H loops of the as-deposited samples. The inset in figures shows a blown up region near the coercive field. A typical “trans-critical shape” of the M-H loop [Fig. 4(a)] for the undoped sample suggests that the film exhibits perpendicular magnetic anisotropy (PMA). Recently, Ji et al. have reported similar type M-H loops for epitaxial $\alpha''$-Fe$_{16}$N$_2$ thin films [14]. Here it was claimed that observed magnetic anisotropy originates due to magnetocrystalline anisotropy in the system, which originates due to tetragonal distortion of bcc Fe lattice as N atoms occupy interstitial positions. Magnetocrystalline anisotropy constant ($K_u$) can be calculated using $K_u = H_k \times M_s / 2$ [14]; where $M_s$ is saturation magnetization and $H_k$ is an anisotropy field which has a value close to $H_s$ saturation field as indicated in Fig. 4(a). We obtain $K_u \sim 10^5$ Jm$^{-3}$, which is close to the reported value [14]. Additionally, obtained values of coercivity ($H_C$) is 10 kA/m. Apart from this, the ratio of remanence magnetization and $M_s$ was found to be 0.4, indicating PMA. For the Fe-Al-N and Fe-Zr-N samples, M-H loops are square shaped with a very small value of $H_C$ (~1 A/m), indicating formation of a soft magnetic phase. Furthermore, an open
region near the saturation field can be seen [as shown in the inset of Figs. 4(b) and 4(c)] indicating presence of hard magnetic phase. To extract the amount of this phase we have fitted the normalized M-H loops assuming a soft and a hard component using the following expression [55,56]:

$$M(H) = \sum_{i=1}^{n} \frac{2M_i^s}{\pi} \arctan \left( \frac{H + H_i^c}{H_i^C} \right) \tan \left( \frac{\pi S_i^3}{2} \right).$$

(1)

Here $M_i^s$ is the saturation magnetization, $H_i^C$ is the coercivity, and $S_i^3$ is ratio of remanent to saturation magnetization ($M_R/M_S$) of the $i$th component of a M-H loop. It was observed that the amount of soft magnetic phase is about 98% and that of hard magnetic phase with $H_C = 12$ kA/m is about 2% in both Al and Zr doped samples.

D. Conversion electron Mössbauer spectroscopy

Mössbauer spectroscopy is a versatile technique to probe the local structure around a resonant nuclei. From our XRD results, discussed in Sec. III A, it was observed that in the as-deposited state Fe-N films have mixed $\alpha''$-Fe$_{16}$N$_2$ and $\alpha$-Fe(N) phases. Whereas in Al or Zr doped samples, only $\alpha$-Fe(N) phase can be seen. Using Mössbauer spectroscopy relative volume fraction of the different Fe-N phases can be obtained. Figures 5(a)–5(c) show selective CEMS spectra of Fe-N (a), Fe-Al-N (b), and Fe-Zr-N (c) thin films in the as-deposited state and after annealing at 425 and 625 K. We fitted the observed CEMS spectra using NORMOS site and DIST programs [57].

CEMS spectrum of the as-deposited Fe-N sample can only be fitted assuming four sextet. Three of them corresponding to the $\alpha''$-Fe$_{16}$N$_2$ phase (hyperfine field = 39, 31.6, and 28.5 T) and the remaining to $\alpha$-Fe (hyperfine field = 33 T), the obtained fitting parameters correlate well with previously reported values [13]. Additionally, area of the fitted sextets can be used to calculate the relative concentration of these phases, which are tabulated in Table II. As can be seen, after annealing at 425 K the values are almost similar to the as-deposited sample, but at a higher annealing temperature of 500 K (not shown) and 625 K, the $\alpha''$-Fe$_{16}$N$_2$ phase disappears and the $\gamma''$ phase starts to grow. The relative area under $\gamma''$ and $\alpha$-Fe phase can be used [17] to calculate nitrogen concentration which comes out to be (11 ± 2) at. %, in agreement with our SIMS measurements.

Moreover, it may be noted here that the intensity ratio of the second and third line ($R_{23}$) in CEMS spectrum can be used to obtain the spin texture [58]. In the absence of any spin texture, $R_{23} = 4$ and $\phi = 90$ deg ($\phi$ is the angle between incident $\gamma$ ray and average spin orientation in the film). The value of $R_{23}$ and $\phi$ reduces as spin gets aligned perpendicularly. In our case the average value of $R_{23}$ = 1.35 and that of $\phi \sim 45$ deg in the as-deposited sample. With annealing $R_{23}$ becomes close to 4 and $\phi \sim 90$ deg, indicating disappearance of spin texture. These results are in agreement with PMA obtained from the M-H loop for the as-deposited undoped sample.

In comparison to Fe-N, CEMS spectra of doped samples are completely different and remain almost similar to the as-deposited samples, even after annealing at 625 K, as expected from XRD results. Besides, it was found that CEMS spectra of Fe-Al-N and Fe-Zr-N samples can only be fitted assuming two components—one corresponding to $\alpha$-Fe(N) phase with hyperfine field about 33 T and another with reduced hyperfine field.

As our magnetization measurements on doped samples show presence of a hard magnetic phase, the phase formed with a reduced hyperfine field may be attributed to it. The values of a hyperfine field for such a hard phase are 23 T for Fe-Al-N and 27 T for Fe-Zr-N samples. The area ratio for this phase comes out to be about 12%. Which could be due to a distribution of a hard phase having different hyperfine fields. Such a hard phase can appear due to some ordering of N atoms [13]. Since in our ED rings any other Fe-N phase cannot be seen, the observed hard phase have originated due to ordering of N atoms within the $\alpha$-Fe(N) phase.

It may be noted that our XRD, TEM, magnetization, and CEMS measurements present comprehensive information about the structural and magnetic properties of samples in the as-deposited state and after annealing at different temperatures. While an undoped sample undergoes phase formation upon annealing, both local and long range stability seem to get significantly improved with Al and Zr doping. However, thermal stability seems to be better with Al than with Zr. In order to understand the mechanism leading to thermal stability, we performed self-diffusion measurements of Fe and N in our samples, which will be discussed in the next section.

<table>
<thead>
<tr>
<th>Temperature</th>
<th>Fe-N</th>
<th>FeAlN</th>
<th>FeZrN</th>
</tr>
</thead>
<tbody>
<tr>
<td>As-deposited</td>
<td>59% ($\alpha''$-Fe$_{16}$N$_2$) + 41% (α-Fe)</td>
<td>89% (α-Fe) + 11% (H)</td>
<td>86% (α-Fe) + 14% (H)</td>
</tr>
<tr>
<td>425 K</td>
<td>60% ($\alpha''$-Fe$_{16}$N$_2$) + 40% (α-Fe)</td>
<td>90% (α-Fe) + 10% (H)</td>
<td>86% (α-Fe) + 14% (H)</td>
</tr>
<tr>
<td>625 K</td>
<td>48% ($\gamma''$) + 52% (α-Fe)</td>
<td>88% (α-Fe) + 12% (H)</td>
<td>88% (α-Fe) + 12% (H)</td>
</tr>
</tbody>
</table>
In Figs. 6(a1)–6(d1) and Figs. 6(a2)–6(d2) a Bragg peak originating due to scattering length \(b_n\) contrast of \(^{57}\)Fe\(^{nat}\)Fe and \(^{15}\)N\(^{nat}\)N, respectively. X-ray reflectivity measurements (not shown) performed on these samples do not show any Bragg peak due to lack of contrast between isotopes. It confirms that films are chemically homogeneous. Since our samples are iron rich and a large difference between the value of \(b_n\) for \(^{nat}\)Fe(=9.45 fm) and \(^{57}\)Fe(=2.3 fm) exists, considerably intense Bragg peak can be seen even with 10 repetitions of bilayers. However, for nitrogen, relatively smaller difference in \(b_n\) for \(^{nat}\)N(=9.36 fm) and \(^{15}\)N(=6.3 fm) and low nitrogen concentration \((\sim 11\) at. %), makes it very difficult to measure nitrogen diffusion. Probably this is the reason that nitrogen self-diffusion has not yet been reported for magnetic Fe-X-N thin films. In order to get the appreciable intensity of Bragg peak, we increased bilayer thickness and the number of repetitions. From fitting of the PNR data [52] measured bilayer period for undoped and Al, Zr, or Ti doped samples are 18.8, 18.4, 17.6, and 17.2 nm, respectively. From Figs. 6(a2)–6(d2) it can be seen, a Bragg peak of appreciable intensity due to \(^{15}\)N\(^{nat}\)N contrast can be clearly observed. Although its intensity is considerably low (as compared to \(^{57}\)Fe/\(^{nat}\)Fe), as expected.

To study self-diffusion, samples were annealed in a vacuum furnace at different temperatures for 1 h at each temperature. For \(^{57}\)Fe/\(^{nat}\)Fe samples, we find that the intensity of the peak does not change with annealing [Figs. 6(a1)–6(d1)] indicating that up to a temperature of 475 K, self-diffusion of iron is negligible. On the other hand, in \(^{15}\)N/\(^{nat}\)N samples, noticeable nitrogen diffusion can be seen even at a temperature of 375 K, and at 425 K nitrogen gets almost completely diffused in all but Al doped samples as shown in Figs. 6(a2)–6(d2). Incidentally, we measured an undoped and an Al doped samples kept at room temperature just after deposition and after a gap of about 1 year (355 days). Inset of Fig. 6 compares PNR patterns of Fe-N (a2) and Fe-Al-N (b2) samples taken immediately after deposition and after 355 days kept at room temperature. It can be seen that N diffusion suppresses with Al doping even at room temperature. This is a clear indication that nitrogen self-diffusion gets remarkably suppressed with Al doping. In contrast to this, with Zr doping behavior of nitrogen diffusion is surprisingly unusual, as Zr doping results in somewhat faster nitrogen diffusion compared to an undoped Fe-N sample.

From the decay in the intensity of Bragg peak self-diffusivity in the samples can be calculated using the following expression [47,59–61]:

\[
\ln \left( \frac{I(t)}{I(0)} \right) = -\frac{8\pi^2D}{d^2}t, \tag{2}
\]

where \(I(0)\) is the intensity of the first order Bragg peak at time \(t = 0\) (before annealing), \(d\) is the bilayer thickness, and \(D\) is diffusivity. Obtained values of \(D\) for Fe-N and Fe-Al-N samples kept at room temperature for about 1 year comes out to be \(2 \times 10^{-25}\) and \(1 \times 10^{-25}\) m\(^2\) s\(^{-1}\), respectively. Information about diffusivity can also be obtained from fitting of PNR data.
FIG. 7. (Color online) Self-diffusivity of nitrogen obtained from (a) PNR and (b) SIMS measurements, solid lines are guide to eye. Typical error bars in the measurements are about the size of scatters.

Following the fitting procedure as mentioned in Sec. III C, obtained values of diffusion length are 3.5 and 2.5 nm for Fe-N and Fe-Al-N samples, respectively, which are in close agreement with values obtained using Eq. (2). It shows that using PNR we can measure diffusivity precisely down to $1 \times 10^{-25}$ m$^2$ s$^{-1}$. Such small values of diffusivity are probably the lowest values ever measured [45,62].

Measured diffusivity at higher annealing temperature gives a snapshot picture for a fixed annealing time, an obtained variation of $D$ with temperature is shown in Fig. 7(a). As mentioned before, we also measured nitrogen diffusion using SIMS and for this purpose we prepared a special trilayer structure $\text{Si(Sub.)|}[\text{Fe-X-natN(110 nm)}|\text{Fe-X-15N(2 nm)}|\text{Fe-X-natN(110 nm)}]$, such structure is expected to give a peak when looking at $^{15}$N depth profile. As samples are annealed broadening of this peak provides information about nitrogen self-diffusion. Applying thin films solution to Fick’s law, the tracer concentration of $^{15}$N with penetration depth (say $x$) can be expressed as [63]

$$c(x,t) = \frac{\text{const.}}{2\sqrt{\pi Dt}} \exp\left(\frac{-x^2}{4Dt}\right).$$

Here $t$ is annealing time and $D$ is the diffusion coefficient. Figure 8 shows SIMS depth profile of Fe-N, Fe-Al-N, and Fe-Zr-N samples annealed at various temperatures. Here again we find that as annealing temperature is increased, broadening of the $^{15}$N peak is more for the Fe-N and Fe-Zr-N samples as compared to the Fe-Al-N sample. Fitting SIMS profile with a Gaussian function according to Eq. (3) yields $D$ as

$$D = \frac{\sigma^2 - \sigma_0^2}{2t}.$$  

Here $\sigma$ is the standard deviation of the Gaussian depth profile before annealing ($t = 0$) and after an annealing time of $t$. Obtained values of $D$ are plotted in Fig. 7(b). It may be noted that the depth resolution of SIMS is relatively poor (as compared to reflectivity). Therefore, absolute values of diffusivity may differ slightly, still the behavior of nitrogen diffusion is similar to that obtained with PNR measurements. Since in the Zr doped sample nitrogen diffusion was so fast that it was not possible to measure it with PNR, in SIMS measurements it can be clearly seen that with Zr doping nitrogen diffusion become even faster as compared to the undoped sample. This is an important result, for deciding effective dopant in Fe-X-N thin films. From the shape of the $^{15}$N depth profiling information about the nitrogen diffusion mechanism can be estimated. In case of grain boundary diffusion it would scale linearly with $x^{6/5} (x = \text{depth})$ [64,65] and would not follow a Gaussian distribution as observed for volume type diffusion. Since in our case a profile can be fitted with a Gaussian, we expect that the N diffusion mechanism to be of volume type, predominantly.

On the basis of the above results, it can be clearly seen that nitrogen self-diffusion gets reduced only with Al doping. We therefore also performed PNR measurements with an isothermal annealing experiment in Fe-N and Fe-Al-N samples at 368, 398, and 413 K for different annealing time. Figures 9(a) and 9(b) shows PNR patterns of Fe-N and Fe-Al-N samples annealed at 368 K for different times. Here
intensity was multiplied by $q_z^2$ to remove decay due to Fresnel reflectivity. On comparing the reflectivity patterns, it can be clearly seen that in an undoped sample significant N diffusion started even at 368 K which increases further with increasing annealing time and attains a state of relaxation, whereas in the Al doped sample only marginal diffusion takes place. Figure 9(c) compares variation of intensity at Bragg peak with time for the Fe-N and Fe-Al-N samples annealed at 413 K. It can be seen that intensity decays exponentially with annealing time. After fitting the data using $I(t) = I(0)\exp(-t/\tau)$, it was observed that relaxation time ($\tau_{\text{relax}}$) for nitrogen diffusion increases by more than an order of magnitude with Al doping. Such increase in $\tau_{\text{relax}}$ provides further insight about involved diffusion mechanism, which is discussed in Sec. IV.

It is well known that, in the relaxed state, diffusivities follow Arrhenius-type behavior given by $D_R = D_0\exp(-E/k_BT)$, with $D_R$ as diffusivity in relaxed state and $D_0$ as the pre-exponential factor, $E$ is activation energy, $T$ is annealing temperature, and $k_B$ is Boltzmann constant. Figure 9(d) shows Arrhenius type behavior of N self-diffusion in Fe-N and Fe-Al-N thin films. A straight line fit to the data gives a value of $\ln(D_0)$ and $E$. For Fe-N and Fe-Al-N samples values of $[\ln(D_0)$ and $E$] are $(-37.39 \pm 1, 0.4 \text{ eV} \pm 0.05)$ and $(-43.42 \pm 1, 0.25 \text{ eV} \pm 0.02)$, respectively. It can be seen that both $\ln(D_0)$ and $E$ decrease with Al doping.

Comparing the value of N diffusivity (e.g., for undoped sample) with those reported in literature (for bulk iron nitride), we find that our values are at least 3–4 orders of magnitude smaller [66]. As mentioned already, our samples are at saturation N concentration ($\sim 11$ at. %), therefore it is expected that a large fraction of interstitial sites are filled with N atoms. Therefore, the probability of obtaining neighboring vacant interstitial sites will be less leading to a suppression in nitrogen diffusivity [63].

In order to get a complete picture about diffusion in our samples, it was required that iron self-diffusion should also be measured. From our neutron reflectivity measurements, Fe self-diffusion was measured by sitting at the Bragg peak position and delayed photons were measured in time differential mode from 40 to 150 ns (within a bunch). The NFS spectra show a quantum beat pattern spread over delayed time, which arises due to interference between various hyperfine fields acting at the resonant nuclei [67].

Following a similar approach as mentioned for neutron reflectivity measurements, Fe self-diffusion was measured by annealing the samples at different temperatures and performing NRR measurements subsequently. Figure 10(a) shows NRR patterns of Fe-N and Fe-Al-N samples in the as-deposited state and after annealing samples at different temperatures. It can be seen that up to a temperature of 473 K, Fe diffusion is negligible (also seen from PNR measurements Fig.6) in both samples. In an undoped sample Fe diffusion is appreciable at 600 K while at 773 K it diffuses completely. Whereas in an Al doped sample, only a marginal diffusion can be seen at 600 K while at 773 K Bragg peak can still be seen. The inset of Fig. 10(a) compares Fe diffusivity obtained from the decay in intensities of the Bragg peak using Eq. (2). As expected, Fe diffusivity suppress significantly with Al doping. In a recent study Fe self-diffusion was measured in ion beam sputtered Fe-N samples prepared using Al and Zr doping and found Fe diffusion suppresses both with Al and Zr doping [69].

NRR measurements in time integral mode were carried out in $\theta-2\theta$ mode and are shown in Fig. 10(a). On the other hand, NFS measurements were performed by sitting at the Bragg peak position and delayed photons were measured in time differential mode from 40 to 150 ns (within a bunch). The NFS spectra show a quantum beat pattern spread over delayed time, which arises due to interference between various hyperfine fields acting at the resonant nuclei [67].

NRR measurements were performed at P01 beamline of PETRA III both in time integral and time differential modes. For $^{57}$Fe the lifetime of the excited state of nucleus is about 140 ns, therefore a 40 bunch mode of PETRA III was used (pulse duration of about 176 ns). In time integral mode, both electronic (prompt with few nanoseconds) and nuclear (delayed 40–140 ns) reflectivities can be measured simultaneously as they occur in different time windows and their scattering amplitude is given by $F = F_{\text{electronic}} + F_{\text{nuclear}}$ [61,68].
with annealing indicating different phase formation, which are correlated with our XRD and CEMS results discussed in Secs. III A and III D. In case of the Al doped sample no appreciable change in the NFS pattern can be observed, it suggests that the local magnetic structure also gets stabilized with Al doping. These results are consistent with our XRD and CEMS measurements.

IV. DISCUSSION

Combining results discussed above, a picture about the diffusion mechanism and the influence of dopants on diffusion can be drawn. We observed that Fe and N self-diffusion takes place in different temperature regimes. Up to a temperature of about 450 K, N diffusion dominates and Fe diffusion is negligible, only above 450 K considerable Fe diffusion can be observed. Importantly, both the structure and the magnetic properties remain almost unchanged even when nitrogen diffuses completely. It indicates that N diffusion has no significant role in the structural or magnetic changes in our samples. On the other hand, variation in the structural and magnetic properties seems to be driven by Fe self-diffusion which starts above 450 K. However, dopants have clear intervention in affecting self-diffusion of both Fe and N. From our TEM measurements we observed that microstructure of the undoped sample is slightly different from doped samples. In spite of that N self-diffusion has similar behavior in undoped and Zr doped samples, but is completely different for Al doped samples. Clearly the difference in microstructure does not correlate with N self-diffusion behavior. Our SIMS measurements also ruled out the possibility of grain boundary diffusion of N which is expected to be highly dependent on the microstructure.

First, we will discuss the role of dopants on influencing N self-diffusion. It is known that up to a concentration of ∼11 at. %, N atoms occupies interstitial sites within the Fe lattice. Numerous studies on self-diffusion behavior of light elements such as H, C, O, N, etc. reveal that they follow interstitial-type diffusion mechanism [70–73]. In the course of interstitial diffusion, N atoms try to find the most equilibrium interstitial sites by crossing a saddle point barrier. Moreover, interstitial diffusion is strongly affected by pressure, which alters available interstitial volume for diffusing N atoms [74]. In case of the undoped sample, due to the absence of any impeding force, N diffusion leads to its redistribution within the lattice. This redistribution favors nitrogen ordering, as observed from the sharpening in the peak corresponding to the α” phase in our XRD results (Fig 1). As mentioned in Sec. III A, with Al doping the average unit cell volume of Fe gets reduced by ∼0.5%. This will also decrease the available interstitial volume for the diffusing N atoms. Therefore, the probability for finding equilibrium interstitial sites will be less resulting in slower N diffusion or a larger relaxation time, as observed with Al doping. On the contrary, with Zr doping the average unit cell volume of Fe gets expanded by ∼2%. In this situation, availability of additional equilibrium interstitial sites may accelerate the diffusion process of N atoms. Similarly, enhanced N diffusion with Ti doping can be understood.

As pointed out earlier, thermal stability of Fe-X-N thin films are significantly affected by self-diffusion of Fe. Our results show that doping of Al has notably reduced the self-diffusion of Fe. Although we find that the structure and the magnetic stability gets improved with both Al as well as Zr doping. It indicates that the atomic size of dopants does not matter in suppressing Fe self-diffusion. It seems that the role of dopants on influencing the self-diffusion of Fe is completely different from N diffusion. Since ΔH_f for nitride formation of dopants is low, there is a large probability that X-N layer may be formed in the grain boundary region, as observed in some reports [25,75]. This X-N layer may act as a diffusion barrier for Fe [76]. Moreover, this barrier layer seems to have multiple effects as it not only suppresses Fe self-diffusion, it also hinders grain growth, leading to improved soft magnetic properties as observed in our samples with Al or Zr doping. The improvement in soft-magnetic properties of Fe-N thin films with dopants was also found in previous reports [34,77,78]. Somewhat superior thermal stability with Al doping can also be understood from the fact that only with Al doping N diffusion suppresses.

V. CONCLUSION

In the present work we have studied the role of Fe and N self-diffusion on influencing the structure, magnetic properties, and thermal stability of Fe-X-N thin films. It was observed that with Al or Zr doping thermal stability gets significantly improved. Additionally, magnetization measurements revealed that soft-magnetic properties also gets improved with dopants. To understand the observed effects, detailed Fe and N self-diffusion measurements were performed. It was found that dopants have clear intervention in affecting Fe and N self-diffusion, however, the mechanism leading to the suppression of Fe and N self-diffusion is different. In case of N self-diffusion, atomic size of dopants plays a crucial role. It was observed that N diffusion gets significantly reduced when the atomic size of dopants is smaller than that of Fe. A dopant with smaller size lead to compression in the Fe lattice, whereas lattice expansion takes place when a larger (than Fe) dopant is used. Such lattice distortion caused by dopants results in alteration of available interstitial volume for diffusing N atoms. On the other hand, Fe self-diffusion gets suppressed with any dopant, if its heat of formation is significantly smaller than that of Fe-N. This happens due to the formation of a diffusion barrier layer which not only suppresses self-diffusion of Fe but also hinders the grain growth leading to improved soft-magnetic properties. In addition, it can be concluded that N diffusion has a less significant role (as compared to Fe) in affecting the thermal instability in Fe-N thin films.

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